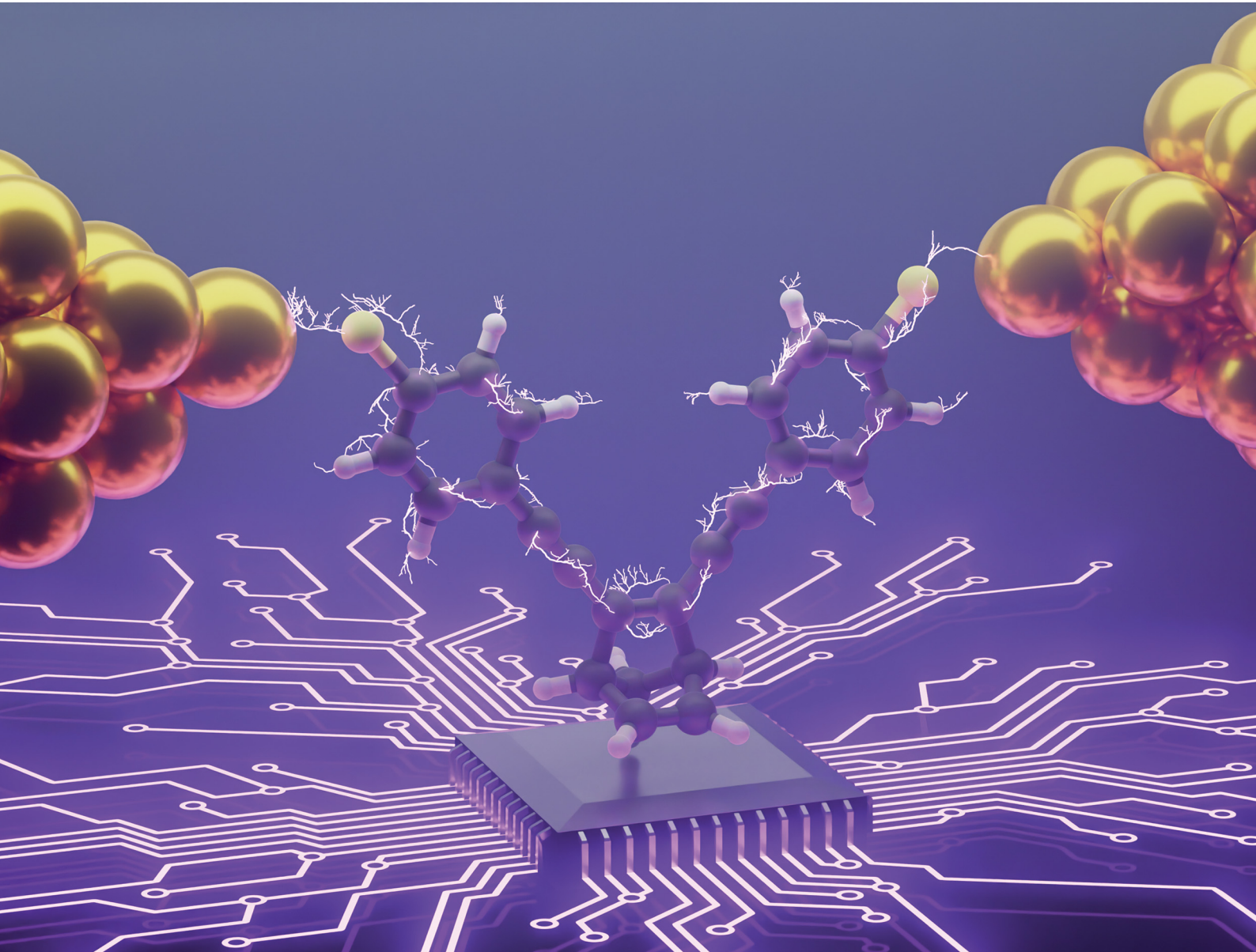


# Journal of Materials Chemistry C

Materials for optical, magnetic and electronic devices

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ISSN 2050-7526
















**PAPER**

Kasper Moth-Poulsen *et al.*  
Exploring the impact of select anchor groups for  
norbornadiene/quadricyclane single-molecule switches



Cite this: *J. Mater. Chem. C*, 2023, 11, 15412

## Exploring the impact of select anchor groups for norbornadiene/quadricyclane single-molecule switches†

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To achieve the ultimate limit of device miniaturization, it is necessary to have a comprehensive understanding of the structure–property relationship in functional molecular systems used in single-molecule electronics. This study reports the synthesis and characterization of a novel series of norbornadiene derivatives capped with thioether and thioester anchor groups. Utilizing the mechanically controllable break junction technique, the impact of these capping groups on conductance across single-molecule junctions is investigated. Among the selection of anchor groups, norbornadiene capped with thioacetate and *tert*-butyl groups exhibits higher conductance ( $G \approx 4 \times 10^{-4} G_0$ ) compared to methyl thioether ( $G \approx 2 \times 10^{-4} G_0$ ). Electronic transmission through the considered set of single-molecule junctions has been simulated. The computational results for electron transport across these junctions align closely with the experimental findings, with the thioacetate- and *tert*-butyl-substituted systems outperforming the methyl thioether-capped derivative. In terms of junction stability, the methyl thioether-capped system is the most resilient, maintaining consistent conductance even after approximately 10 000 cycles. Meanwhile, the likelihood of observing molecular plateaus in both the thioacetate- and *tert*-butyl-substituted systems declines over time. These findings substantially advance both the design and understanding of functional molecular systems in the realm of single-molecule electronics, particularly in the context of molecular photoswitches.

Received 26th July 2023,  
Accepted 4th October 2023

DOI: 10.1039/d3tc02652c

rsc.li/materials-c

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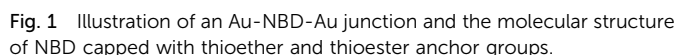
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† Electronic supplementary information (ESI) available: Full description of the synthesis, simulation, and chemical characterization of the investigated systems, including <sup>1</sup>H-NMR, <sup>13</sup>C-NMR, HRMS, SCXRD, MCBJ, and computational data. CCDC 2269540. For ESI and crystallographic data in CIF or other electronic format see DOI: <https://doi.org/10.1039/d3tc02652c>

## Introduction

The incorporation of organic molecules into single-molecule devices stands as a transformative pathway to decreasing the dimensions of electronic devices.<sup>1–4</sup> These pioneering systems have showcased an array of impressive functionalities, ranging from the intricate dynamics of (photo)switching phenomena<sup>5–9</sup> to the roles played by single-molecule diodes<sup>10,11</sup> and transistors.<sup>12,13</sup> Moreover, the study of single-molecule junctions has helped unveil intricate details of electron<sup>14,15</sup> and heat transport<sup>16,17</sup> at the molecular scale.

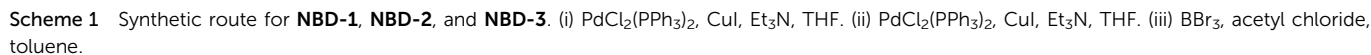
Central to the construction of a single-molecule junction are three fundamental components: the structure of the core molecule, the chemical anchor groups, and the electrodes themselves. The intricate design of both the molecular structure and the anchor groups wields a profound influence on the conductance observed across metal–molecule–metal junctions, unraveling new possibilities for tailoring and fine-tuning electronic properties.<sup>18</sup> Through meticulous modifications of the



The presented investigation combines experimental and computational approaches to study the conductance of three distinct thioether- and thioester-substituted norbornadiene (NBD) derivatives (Fig. 1). NBD is a bicyclic hydrocarbon that undergoes photoisomerization to the metastable quadricyclane (QC) form when exposed to light.<sup>22,23</sup> The NBD/QC photoswitch pair has attracted significant attention, demonstrating remarkable versatility in diverse applications including energy storage,<sup>24–27</sup> diagnostics,<sup>28</sup> and single-molecule devices.<sup>22,23</sup> Prior studies employing scanning tunneling microscopy break

Given the considerable influence that experimental setup, molecular length, and anchor groups can exert on conductance properties,<sup>29–33</sup> this study embarks on investigating a novel series of thioether- and thioester-capped NBD molecules, characterized by reduced lengths and encompassing three distinct anchor groups: *tert*-butyl thioether (**NBD-1**), thioacetate (**NBD-2**), and methyl thioether (**NBD-3**). To achieve this, a modified synthetic strategy was employed, capitalizing on palladium-catalyzed cross-coupling reactions to construct the molecular systems. The effects of the selected anchor groups on conductance are thoroughly examined, providing insights into the complex conduction properties of these NBD derivatives. The analysis employs the mechanically controllable break junction technique (MCBJ), a reliable method for precise measurements and control of electrode spacing, in conjunction with electron transport simulations.

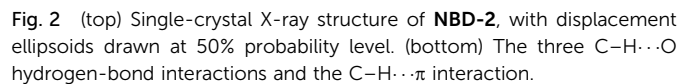
The three investigated NBD derivatives were synthesized through consecutive Sonogashira cross-coupling reactions,<sup>34</sup> as shown in Scheme 1, wherein the different thioether and thioester anchor groups were attached to 2,3-dibromonorbornadiene (**4**). *S*-(4-Ethynylphenyl) ethanethioate has been introduced into molecular wires previously through a reaction with 1,4-dibromobenzene.<sup>35</sup> Here, different classical conditions were employed to couple *S*-(4-ethynylphenyl) ethanethioate with 2,3-dibromonorbornadiene. In order to overcome the challenge posed by the potential degradation of the





Another intriguing observation is the time-dependent decrease in the presence of Class 1 for **NBD-1** and **NBD-2**. This trend is illustrated in Fig. 4a: during the initial 2000 traces, Class 1 is predominant and clearly visible in the two-dimensional histogram. In the subsequent 2000 traces (from 2001 to 4000), the high-conductance plateau remains visible

From the crystal-structure analysis of **NBD-2**, it can be noted that the two benzene rings in the structure exhibit a slight skewing, with an angle of 28 degrees between their respective normal planes (ESI<sup>+</sup>), Fig. S11. A key insight gained from the crystal structure analysis is the precise molecular dimensions. In particular, the sulfur-sulfur distance, which represents the



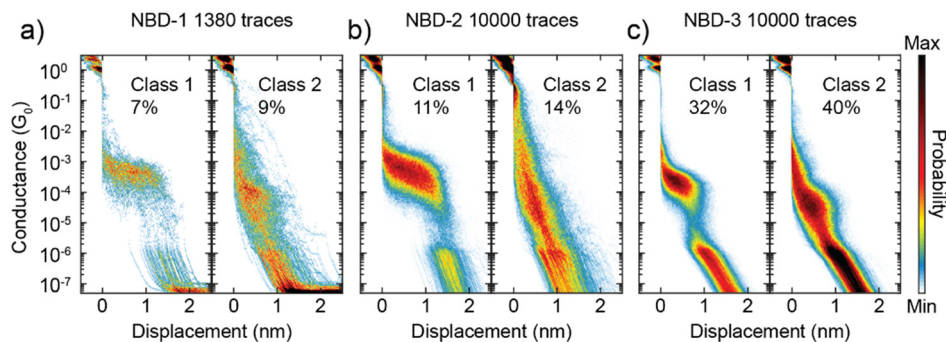


Fig. 3 Two-dimensional conductance-displacement histograms of Class 1 (left) and Class 2 (right), derived from the MCBJ measurements of (a) **NBD-1**, (b) **NBD-2**, and (c) **NBD-3**. The number in the inset is the yield of the corresponding class.

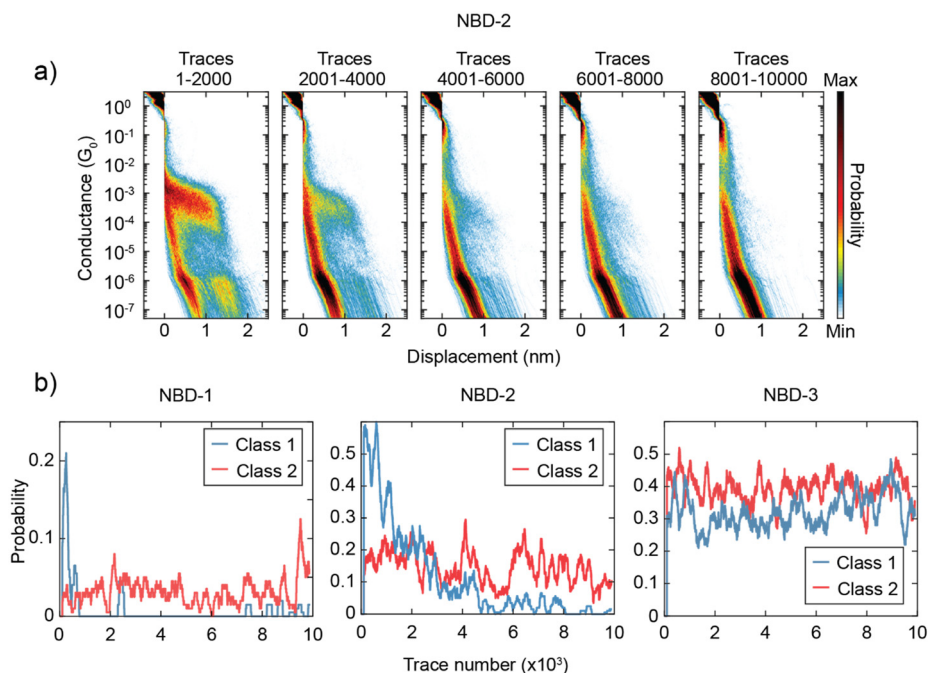


Fig. 4 (a) Two-dimensional histograms of the raw data of **NBD-2** constructed using subsequent intervals of 2000 traces (corresponding roughly to two hours of measurement). (b) Time evolution of the probability of measuring Class 1 (red) and Class 2 (blue) for **NBD-1** (left), **NBD-2** (center), and **NBD-3** (right).

but loses its dominance. Between trace 4001 and trace 6000, Class 1 can still be observed, albeit with a considerably lower yield. After trace 6000, Class 1 traces appear to be essentially absent. To gain further insight into this phenomenon, the probability of measuring traces belonging to Class 1 or Class 2 as the measurement progressed was calculated. The probability was computed over intervals of 200 traces (equivalent to approximately 25 minutes of measurement) centered on each trace, excluding the first and last 100 traces due to incomplete intervals. The result of this analysis is presented in Fig. 4b. For **NBD-1** and **NBD-2**, the probability of measuring Class 1 experiences a sharp decay within the first 4000 traces, ultimately vanishing, while the probability of Class 2 remains relatively stable. In contrast, **NBD-3** does not exhibit a decay in the probability of either class.

The interpretation of the origin of the two classes is not straightforward. Although the conductance values align with

those reported in the literature,<sup>22,23</sup> Class 1 displays a plateau length greatly exceeding what would be anticipated based on the SCXRD structure. Consequently, this elongated plateau cannot be solely attributed to a sulfur-to-sulfur molecular connection. Additional factors, such as sulfur dimerization or molecular strain, could be contributing factors, although these mechanisms remain speculative based on the available data. In contrast, Class 2 exhibits a plateau length of 0.9 nm (1.4 nm electrode-electrode distance), more closely aligning with expectations based on literature on comparable compounds.<sup>22,23</sup>

## Electron transport calculations

To gain further insights into the intricate nature of how the anchor groups affect the electron-transport properties,



simulations of the electron transport across the considered molecular junctions have been carried out. Given the similarity between the measured conductance of the **NBD-1** and **NBD-2** systems, the possibility of both systems undergoing deprotection, resulting in the same thiolate, has to be taken into account. While literature on *tert*-butyl thioether-functionalized molecular wires is limited,<sup>42</sup> the steric bulk of the group, in combination with the similarity in measured conductance to the thioacetate-capped system—which is known to undergo deprotection<sup>43–46</sup>—suggests that the **NBD-1** system may also undergo some degree of deprotection. This might also be part of the explanation for the noted stability of the junctions. Specifically, the likelihood of measuring Class 1 for the **NBD-1** and **NBD-2** systems diminishes significantly over time. In contrast, the probability for the **NBD-3** system remains consistent, suggesting that methyl thioether is the most resilient protection group out of the three. Additionally, this implies that the **NBD-1** and **NBD-2** systems face comparable challenges regarding stability, possibly due to undergoing some level of *in situ* deprotection.

Here, a complete deprotection of both systems has been assumed for the simulations, resulting in near identical transmission probabilities across the considered 5 eV energy window. The geometries of the two systems were optimized *in vacuo*, including the *tert*-butyl thioether and thioacetate groups, prior to the electron transport calculations. The terminal groups were then removed as the systems were placed in the gold junctions. The same was done for **NBD-3**, albeit without removing the terminal methyl groups. Full details regarding the level of theory and the computational approach are presented in the ESI,<sup>†</sup> Section S4.

The theoretical structures contain sulfur–sulfur distances ranging from 1.1343 nm to 1.2911 nm (Fig. 5) and are thus qualitatively comparable to the SCXRD-obtained structure of **NBD-2** (1.1933 nm). Additionally, the predicted electronic transmission across the three junctions, displayed in Fig. 6, qualitatively reproduces the experimental findings. Mainly, a noticeable decrease in transmission around the Fermi energy level is seen going from **NBD-1** and **NBD-2** to **NBD-3**.

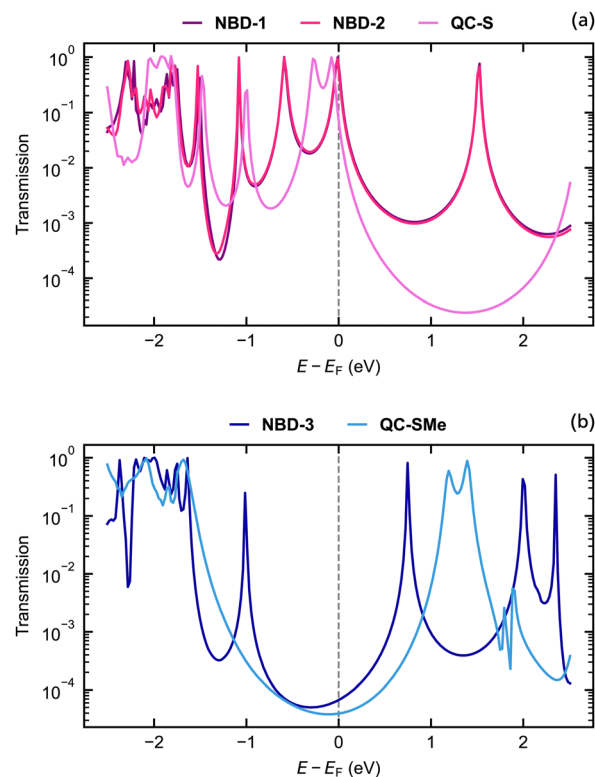


Fig. 6 Electronic transmission calculated using density functional theory through the (a) **NBD-1**, **NBD-2**, **QC-S**, (b) **NBD-3**, and **QC-SMe** junctions.

It is important to note that in systems with thiol-based anchor groups, the transmission is typically governed by a resonance associated with the highest occupied molecular orbital (HOMO), which typically aligns with the Fermi energy level of the gold electrodes.<sup>47,48</sup> The results presented in Fig. 6 demonstrate the same phenomenon, as all three NBD derivatives exhibit a transmission peak near the Fermi energy corresponding to their respective HOMO energies. The tails of these peaks are the main contributors to the predicted transmission at the Fermi energy level, although for the deprotected

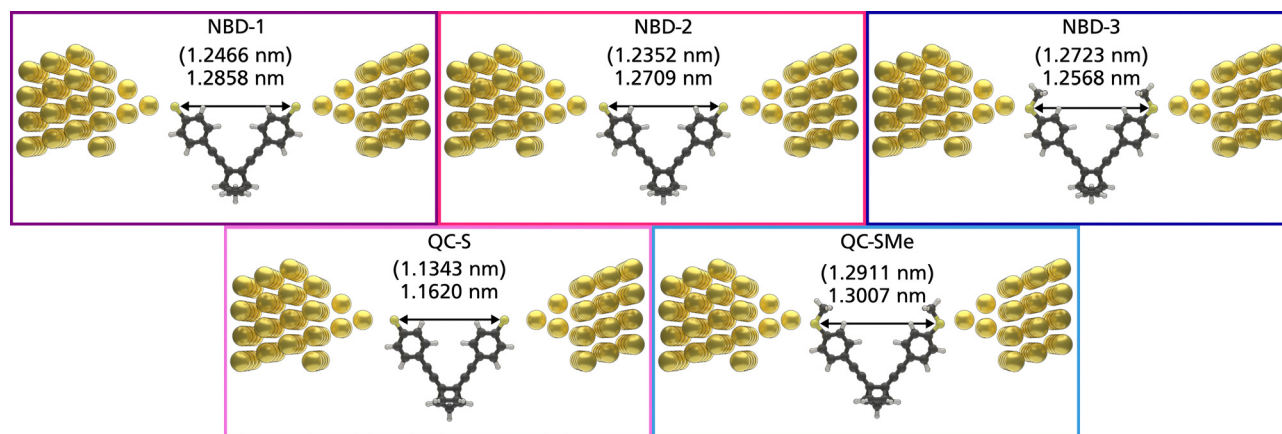


Fig. 5 Depictions of the non-optimized single-molecule junctions. The lengths in parentheses are the sulfur–sulfur distances present in the vacuum-optimized structures, while the values below are the sulfur–sulfur distances in the relaxed junction geometries.



derivatives, the HOMO-induced transmission peak overlaps with the Fermi energy level. The placement of the Fermi energy level thus plays a crucial role in the determination of qualitative aspects of the junctions and may also affect the predicted transmission gap between different molecular junctions.

While not established in this particular study, previous research on the NBD/QC pair in a metal junction has shown switching behavior from NBD to QC during measurements.<sup>24,25</sup> It is important to acknowledge that the NBD derivatives being investigated may undergo varying degrees of switching, which can significantly impact the results as the transition from NBD to QC leads to a decrease in conductance. In the NBD state, there is a conjugated pathway from one substituent to the other through the double  $\pi$ -bond, whereas the transition to QC breaks this conjugated pathway, resulting in lower conductance. Due to the presence of a  $\pi$ -conjugated pathway through the NBD molecule, where the energy gap between occupied and virtual orbitals is smaller, the decay of the HOMO-induced peak occurs at a slower rate compared to the QC systems. Consequently, the NBD derivatives exhibit higher transmission at the Fermi energy than their QC counterparts.

From comparable electron transport calculations for the QC isomer of **NBD-1** (denoted **QC-S**), a transmission ratio of 9.58 at the Fermi energy is predicted. The ratio between the **NBD-3** system and its counterpart, **QC-SMe**, is 1.71. The **NBD-3/QC-SMe** ratio is thus lower than the theoretical and experimental ratios found for a similar NBD/QC derivative pair, while the **NBD-1/QC-S** ratio is comparable.<sup>22</sup> The switching from the NBD molecule to the QC form could thus be at the origin of the two classes of conductance observed in the measurements. In previous studies on similar NBD/QC derivatives,<sup>25</sup> the transition was proven to be possible at low yields even at a small voltage bias. However, the presence of other mechanisms, such as the formation of junctions in which the molecule binds with different coordination to the gold surface,<sup>29</sup> cannot be excluded.

## Conclusions

A novel family of NBD capped with thioether and thioester anchor groups has been introduced and thoroughly investigated to understand their conductive properties. Through meticulous MCBJ measurements, a consistent observation emerged across the series of NBD compounds, revealing the presence of high-conductance plateaus at approximately  $10^{-4} G_0$ , accompanied by lower plateaus around  $10^{-5} G_0$ . As anticipated based on prior research, **NBD-3** demonstrated lower conductance compared to **NBD-2** and **NBD-1**.

Notably, for **NBD-3**, the probability of measuring each conductance class remained stable throughout the measurement, indicating consistent behavior. In contrast, for **NBD-1** and **NBD-2**, the probability of measuring the high-conductance class decreased over time, suggesting a time-dependent change in their conductive properties. This might be a consequence of *in situ* deprotection, in combination with the conditions under

which the measurements were carried out. This observation highlights the dynamic nature of molecular junctions and emphasizes the significance of monitoring behavior during extended measurements. Simulations of the considered single-molecule junctions demonstrated the same conductance pattern across the selection of anchor groups, with the **NBD-1** and **NBD-2** systems outperforming the methyl thioether **NBD-3** system. Additionally, simulations of the corresponding QC systems showed a considerable drop in conductance compared to the respective NBD systems. The ratio between the conductance of the NBD and QC states indicates that a switch from one state to the other might explain—at least partially—the different conductance classes observed in the MCBJ measurements.

Overall, this study contributes to the understanding of molecular junctions and their conductive properties. The synthesis of a new family of NBD molecules, combined with comprehensive experimental measurements and computational simulations, has provided valuable insights into the behavior and potential applications of these molecules in nanoelectronics and molecular-scale devices.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

KMP acknowledges funding from the Catalan Institution for Research and Advanced Studies (ICREA), the European Research Council (ERC) through ERC-CoG PHOTOTHERM, and the European Union project ESiM 101046364. The Swedish NMR Centre at the University of Gothenburg is acknowledged for its support.

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